

Voltage Variable Absorptive Attenuator DC - 2 GHz

AT-332, AT-337

V 2.00

Features

- Available in Ceramic and TO-5 packages
- 40 dB Matched Attenuation
- Low Insertion Loss

Guaranteed Specifications¹

(From -55°C to + 85°C)

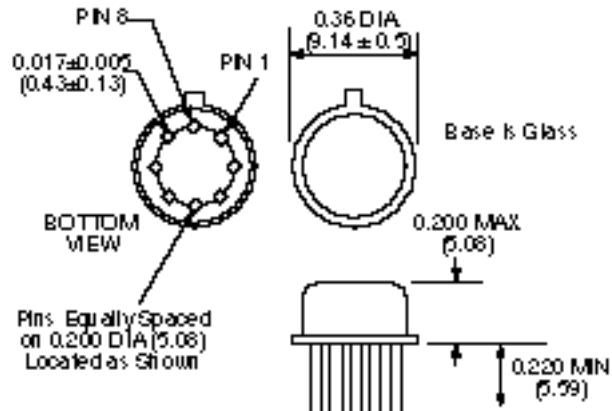
Frequency Range	DC – 2.0 GHz	
Insertion Loss	DC – 2.0 GHz	1.5 dB Max
	DC – 1.0 GHz	1.2 dB Max
VSWR	AT-332	AT-337
	DC – 2.0 GHz	1.4:1
	DC – 1.0 GHz	1.25:1
Attenuation (Matched) @ 25°C	DC – 2.0 GHz	40 dB Min
Flatness (Peak to Peak)	0-20 dB Attenuation	1.0 dB Max
	0-30 dB Attenuation	2.0 dB Max
	0-40 dB Attenuation	3.0 dB Max
Attenuation vs Temperature (Relative to 25°C)	0 to 20 dB Attenuation	±2.5 dB
	0 to 30 dB Attenuation	±4.0 dB
	0 to 40 dB Attenuation	±6.0 dB

Operating Characteristics

Impedance	50 Ohms Nominal	
Switching Characteristics		
Trise, Tfall (10% to 90%)		14 ns Typ
Ton, Toff (50% CTL to 90%/10% RF)		22 ns Typ
Transients (in band)		14 mV Typ
Input Power for 1 dB Compression		
Attenuation Level	0 dB	
0.05 GHz	21	
0.5 GHz to 2.0 GHz	27	dBm Typ
Intermodulation Intercept Point (for two-tone input power up to +5 dBm)		
Intercept Points	IP2	IP3
Attenuation Level (dB)	0 5 10	0 5 10
0.05 GHz	54 43 39	39 33 30
0.5 to 2 GHz	65 54 49	47 44 38
Phase Shift (Relative to 0 dB Attenuation)		
Attenuation Level	10 dB	20 dB
0.5 GHz	0.1	3
2.0 GHz	0.4	12
35		
60		Deg Typ
Control Voltages		
A input (Shunt FETS)	0 to -4V @ 100 µA Max	
B input (Series FETS)	0 to -4V @ 100 µA Max	

1. All specifications apply with 50 ohm connected to all RF Ports.
2. Contact the factory for standard or custom screening requirements.

AT-332 (TO-5-4)

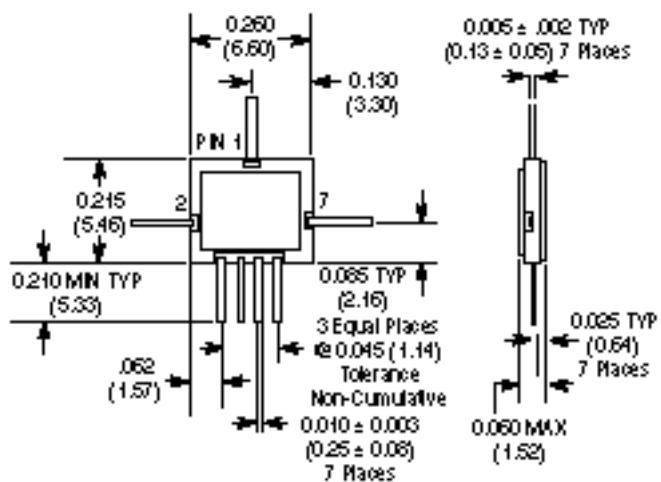


Bottom of Case Is AC Ground

Dimensions in () are in mm.

Unless Otherwise Noted .xxx = ±0.010 (xx = ±0.25)
.xx = ±0.02 (x = ±0.5)

AT-337 (CR-2 w/o Pin 1)



Bottom of Case Is AC Ground

Dimensions in () are in mm.

Unless Otherwise Noted: xxx = ± 0.010 (xx = ± 0.25)
.xx = ± 0.02 (x = ± 0.5)

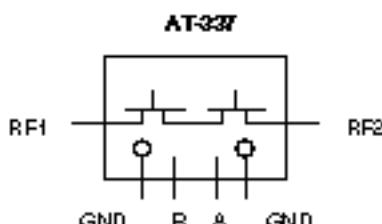
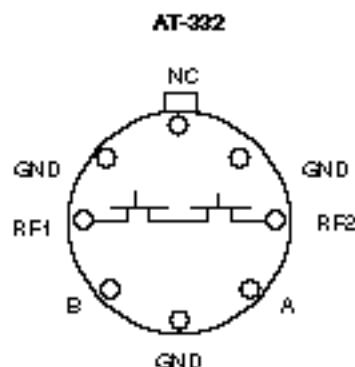
Ordering Information

Model No.	Package
AT-354 PIN	Dual Inline

Absolute Maximum Ratings

Parameter	Absolute Maximum ¹
Max. Input Power	
0.05 GHz	+27 dBm
0.5 – 2.0 GHz	+30 dBm
Control Voltage	+5V, -8.5V
Operating Temperature	-55°C to +125°C
Storage Temperature	-65°C to +150°C

Functional Schematics (Top View)



1. Operation of this device above any one of these parameters may cause permanent damage.

Typical Performance

